NSN 5961-01-310-1836

A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-310-1836 **Inclosure Material:** Ceramic or plastic **Overall Length:** Between 0.776 inches and 0.799 inches **Terminal Length:** Between 0.559 inches and 0.582 inches **Overall Height:** Between 0.185 inches and 0.209 inches **Overall Width:** Between 0.602 inches and 0.625 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-247 **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak reverse voltage all semiconductor device diode and 1.3 forward voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 15.00 amperes forward current, average absolute all semiconductor device diode **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: